

Abstracts

High Burnout Gallium Arsenide Schottky Barrier Diodes

T.H. Oxley, G.H. Swallow and A. Hansom. "High Burnout Gallium Arsenide Schottky Barrier Diodes." 1972 G-MTT International Microwave Symposium Digest of Technical Papers 72.1 (1972 [MWSYM]): 58-60.

This paper discusses the results of a programme to investigate the burnout phenomena of gallium arsenide Schottky barrier mixer diodes with regard to radar system t.r. cell leakage, and describes the performance of X-band high burnout diodes.

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